1.6 Ω On Resistance, \pm 5 V, \pm 12 V, and \pm 3 V Quad SPST Switches

DESCRIPTION

The DG9424E, DG9425E, DG9426E are monolithic quad single-pole-single-throw analog switches. The G9424E and DG9425E differ only in that they respond to opposite logic levels. The DG9426E has two normally open and two normally closed switches. It can be given various configurations, including four SPST, two SPDT, and one DPDT.

Using BiCMOS wafer fabrication technology allows the DG9424E, DG9425E, and DG9426E to operate on single and dual supplies. Single supply voltage ranges from 3 V to 16 V while dual supply operation is recommended with \pm 3 V to \pm 8 V. Each switch conducts equally well in both direction when on, and blocks input voltages up to the supply levels when off.

The low and flat on resistance over the full input signal voltage rang bring excellent linearity, reduce insertion loss and signal distortion, make them ideal for data acquisition and programmable gain control applications. These switch characters also make them ideal fit for audio signal switch and reed relay replacement.

The DG9424E, DG9425E, DG9426E feature low power dissipation, fast switching speed, and low voltage logic control threshold. Proprietary design enables the low charge injection that minimize the switching transient.

Operation temperature is specified from -40 °C to +85 °C. The DG9424E, DG9425E, DG9426E are available in 16 lead TSSOP packages.

FEATURES

- 3 V to 16 V single supply or ± 3 V thru ± 8 V dual supply operation
- 1.6 Ω typical on resistance
- 3 V logic compatible for control
- · Bi-directional rail to rail signal switching
- · Fast switching speed
- < 0.2 nA switch on leakage
- Break-before-make switching DG9426

BENEFITS

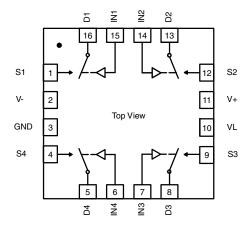
- Wide operation voltage range
- · Low signal errors and distortion
- · Fast switching time
- Simple interfacing

APPLICATIONS

- · Automatic test equipment
- · Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- · Communication systems
- · Audio and video signal routing
- Relay replacement
- Battery powered systems
- Computer peripherals
- Audio and video signal routing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

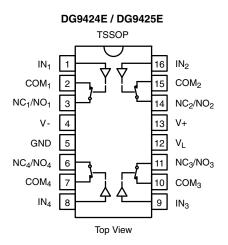
QFN-16 (4 mm x 4 mm)

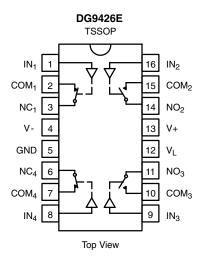




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FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





TRUTH TABLE								
LOGIC	DG9424E	DG9425E						
0	OFF	ON						
1	ON	OFF						

TRUTH TABLE							
LOGIC	SW ₁ , SW ₄	SW ₂ , SW ₃					
0	ON	OFF					
1	OFF	ON					

ORDERING INFORMATION									
TEMP. RANGE	PACKAGE	PART NUMBER	PART MARKING	STD PACK QUANTITY					
		DG9424EDQ-T1-GE3	9424E	Tape and reel 3000 units					
-40 °C to +85 °C	16-pin TSSOP	DG9425EDQ-T1-GE3	9425E	Tape and reel 3000 units					
-40 C to +65 C		DG9426EDQ-T1-GE3	9426E	Tape and reel 3000 units					
	16-pin QFN (4 mm x 4 mm)	DG9424EDN-T1-GE4	9424E	Tape and reel 2500 units					

ABSOLUTE MAXIMUM RA	TINGS		
PARAMETER		LIMIT	UNIT
V+ to V-		-0.3 to +18	
GND to V-		18	V
V _L		(GND - 0.3) to (V+) + 0.3	V
IN, COM, NC, NO ^a		(V-) - 0.3 to (V+) + 0.3	
Continuous current (NO, NC, COM p	ns)	100	να Λ
Peak current, S or D (pulsed 1 ms, 10) % duty cycle)	200	mA
Storage temperature		-65 to +150	°C
Power dissipation (package) ^b	16 min TCCOD (450	mW
Thermal resistance ^b	16-pin TSSOP ^c	178	°C/W
ESD human body model (HBM); per	ANSI / ESDA / JEDEC® JS-001	>1500	V
Latch up current, per JESD78D		400	mA

Notes

- a. Signals on NC, NO, COM or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings
- b. All leads welded or soldered to PC board
- c. Derate 7 mW/°C above 25 °C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



SPECIFICATIONS a Sing	le Supply 1	2 V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. b	-40	UNIT		
		V+ = 12 V, V- = 0 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V^f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog signal range ^e	V _{ANALOG}		Full	0	-	12	V
On-resistance	R _{ON}	V+ = 10.8 V, V- = 0 V	Room	-	1.6	3	Ω
On resistance	TON	I_{NO} , $I_{NC} = 50$ mA, $V_{COM} = 2/9$ V	Full	-	-	4	32
Digital Control							
Input current	I _{INL} or I _{INH}		Full	-1	0.01	1	μA
Dynamic Characteristics							
Turn-on time ^e	+		Room	-	36	51	
rum-on time •	t _{ON}	$R_L = 300 \Omega, C_L = 35 pF$	Full	-	-	65	
Turn-off time e	t _{OFF}	V_{NO} , $V_{NC} = 5$ V, see fig. 2	Room	-	20	35	ns
rum-on time °			Full	-	-	44	
Break-before-make time delay ^e	t _D	DG9426E only, V_{NO} , V_{NC} = 5 V R_L = 300 Ω , C_L = 35 pF	Room	2	-	-	
Charge injection e	Q _{INJ}	V_g = 0 V, R_g = 0 Ω , C_L = 1 nF	Room	-	38	-	рС
Off-isolation ^e	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$	Room	-	-56	-	- dB
Channel-to-channel crosstalk e	X _{TALK}	f = 1 MHz	Room	-	-77	-	
NO NO eff constitution 6	C _{NO(off)}		Room	_	49	_	_
NO, NC off capacitance e	C _{NC(off)}	C 4 MIL		-		-	
COM off capacitance e	C _{COM(off)}	f = 1 MHz	Room	-	37	-	pF
Channel on capacitance e	C _{COM(on)}		Room	-	89	-	
Power Supplies							
Desitive several several			Room	-	0.02	1	
Positive supply current	l+		Full	-	-	5	
			Room	-1	-0.002	-	μΑ
Negative supply current	I-		Full	-5	-	-	
Laster and a second		$V_{IN} = 0$ or V_L	Room	-	0.002	1	
Logic supply current	ΙL		Full	-	-	5	
On all and	I _{GND}		Room	-1	-0.002	-	
Ground current			Full	-5	-	-	



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PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 5 V, V- = 5 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V^f$		MIN. d	TYP. °	MAX. d	
Analog Switch							
Analog signal range ^e	V _{ANALOG}		Full	-5		5	V
On-resistance	R _{ON}	V+ = 4.5 V, V- = -4.5 V	Room	-	1.9	3.3	Ω
OTI-TESISTATICE	TION	I_{NO} , $I_{NC} = 50 \text{ mA}$	Full	-	-	4.3	22
	I _{NO(off)}		Room	-1	-	1	
Switch off leakage current	I _{NC(off)}	V+ = 5.5 V, V- = -5.5 V	Full	-10	-	10	
Switch on leakage current	la a. v. m	$V_{COM} = \pm 4.5 \text{ V}, V_{NO}, V_{NC} = \pm 4.5 \text{ V}$	Room	-1	-	1	nA
	I _{COM(off)}		Full	-10	-	10	11/4
Channel on leakage current	1	V+ = 5.5 V, V- = -5.5 V,	Room	-1	-	1	ŀ
Channel on leakage current	ICOM(on)	V_{NO} , $V_{NC} = V_{COM} = \pm 4.5 \text{ V}$	Full	-10	-	10	
Digital Control							
Input current ^a	I _{INL} or I _{INH}		Full	-1	0.05	1	μΑ
Dynamic Characteristics							
Turn-on time ^e		$R_1 = 300 \Omega, C_1 = 35 pF$	Room	-	48	67	ns
rum-on time °	t _{ON}		Full	-	-	81	
T "" 0		V_{NO} , $V_{NC} = \pm 3.5 \text{ V}$, see fig. 2	Room	-	34	57	
Turn-off time ^e	t _{OFF}			-	-	67	113
Break-before-make time delay ^e	t _D	DG9426E only, V_{NO} , V_{NC} = 3.5 V R_L = 300 Ω , C_L = 35 pF	Room	2	-	-	
Charge injection e	Q _{INJ}	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	112	-	рС
Off isolation e	OIRR	D 5000 5 7 5 1 MHz	Room	-	-56	-	٩D
Channel-to-channel crosstalk e	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$	Room	-	-82	-	dB
Source off capacitance e	C _{NO(off)} C _{NC(off)}		Room	-	38	-	
Drain off capacitance e	C _{COM(off)}	f = 1 MHz	Room	-	38	-	pF
Channel on capacitance e	C _{COM(on)}		Room	-	89	-	
Power Supplies							
Positive supply current e	I+		Room	-	0.03	1	
т общее вирру очнени	IT'		Full	-	-	5	
Negative supply current ^e	I-		Room	-1	-0.002	-	
	1-	$V_{IN} = 0$ or V_{L}	Full	-5	-	-	μΔ
Logic supply current ^e	ΙL	AIN — O OL AE	Room	-	0.002	1	μA
Logic supply culterit	'L		Full	-	-	5	
Ground current e	lave-		Room	-1	-0.002	-]
Ground current ^e	I _{GND}		Full	-5	-	-	Ĭ



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SPECIFICATIONS a Single	e Supply 5	V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	-40	UNIT		
		V+ = 5 V, $V- = 0 VV_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog signal range e	V _{ANALOG}		Full	-	-	5	V
On-resistance e	R _{ON}	V+ = 4.5 V, I _{NO} , I _{NC} = 50 mA	Room	-	3.1	4.8	Ω
On-resistance -	HON	v+ = 4.5 v, INO, INC = 50 IIIA	Full	-	-	5.8	22
Dynamic Characteristics							
Turn-on time e	+		Room	-	62	78	
rum-on time °	t _{ON}	$R_L = 300 \Omega, C_L = 35 pF$	Hot	-	-	106	ns
Turn-off time ^e	t _{OFF}	V_{NO} , $V_{NC} = 3.5 \text{ V}$, see fig. 2	Room	-	29	44	
rum-on time *			Hot	-	-	56	
Break-before-make time delay ^e	t _D	DG9426E only, V_{NO} , V_{NC} = 3.5 V R_L = 300 Ω , C_L = 35 pF	Room	5	-	-	
Charge injection ^e	Q _{INJ}	$V_g = 0 \text{ V}, \text{ R}_g = 0 \Omega, \text{ C}_L = 1 \text{ nF}$	Room	-	10	-	рС
Power Supplies							
Decitive events events	l+		Room	-	0.02	1	
Positive supply current ^e	I+		Hot	-	-	5	
Negative events everent 6	I-		Room	-1	-0.002	-	
Negative supply current ^e	I-	V 0 0 7 V	Hot	-5	-	-	
Lacia aumah, augrant 6		$V_{IN} = 0$ or V_L	Room	-	0.002	1	μΑ
Logic supply current ^e	IL		Hot	ı	1	5	
Ground current ^e	1		Room	-1	-0.002	-	
Ground current "	I _{GND}		Hot	-5	-	-	



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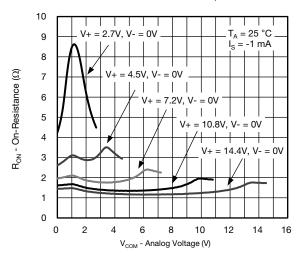
SPECIFICATIONS a Sing	le Supply 3	V						
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT	
		V+ = 3 V, V- = 0 V $V_L = 3 V, V_{IN} = 2.4 V, 0.4 V f$		MIN. d	TYP. c	MAX. d		
Analog Switch								
Analog signal range e	V _{ANALOG}		Full	0	-	3	V	
On-resistance	R _{ON}	V+ = 2.7 V, V- = 0 V	Room	ı	6	-	Ω	
On-resistance	HON	I_{NO} , $I_{NC} = 5$ mA, $V_{COM} = 0.5$, 2.2 V	Full	-	-	-	22	
	I _{NO(off)}		Room	-1	-	1		
Switch off leakage current ^a	I _{NC(off)}	V+ = 3.3 V, V- = 0 V	Full	-10	-	10		
Switch on leakage current "		$V_{COM} = 0.3, 3 \text{ V}, V_{NO}, V_{NC} = 3, 0.3 \text{ V}$	Room	-1	-	1	nA	
	I _{COM(off)}		Full	-10	-	10	IIA	
Channel on leakage ourrent ?		V+ = 3.3 V, V- = 0 V,	Room	-1	-	1		
Channel on leakage current a	I _{COM(on)}	$V_{NO}, V_{NC} = V_{COM} = 0.3, 3 V$	Full	-10	-	10		
Digital Control e								
Input current	I _{INL} or I _{INH}		Full	-1	0.005	1	μΑ	
Dynamic Characteristics								
Turn-on time			Room	-	140	-	ns	
rum-on time	t _{ON}	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	Full	ı	-	193		
Turn-off time	+	V_{NO} , $V_{NC} = 1.5 \text{ V}$, see fig. 2	Room	-	65	-		
rum-on time	t _{OFF}		Full	-	-	89		
Break-before-make time delay	t _D	DG9426E only, V_{NO} , V_{NC} = 1.5 V R_L = 300 Ω , C_L = 35 pF	Room	5				
Charge injection e	Q _{INJ}	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	15	-	рС	
Off isolation e	OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room	-	-56	-	dB	
Channel-to-channel crosstalk e	X _{TALK}	f = 1 MHz	Room	-	-80	-	иь	
0	C _{NO(off)}		Doom	_	F0			
Source off capacitance e	C _{NC(off)}	f _ 1 MU-	Room	_	53	_	nE.	
Drain off capacitance e	C _{COM(off)}	f = 1 MHz	Room	-	42	-	pF	
Channel on capacitance e	C _{COM(on)}		Room	-	92	-		

Notes

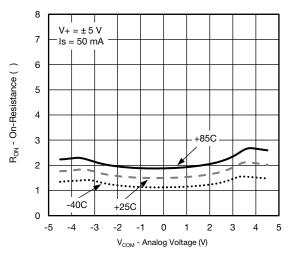
- a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test
- b. Room = 25 °C, Full = As determined by the operating temperature suffix
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
- e. Guaranteed by design, not subject to production test
- f. V_{IN} = Input voltage to perform proper function

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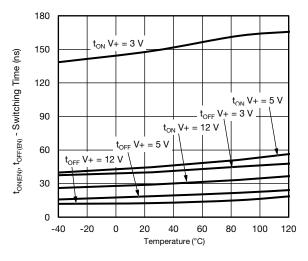
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



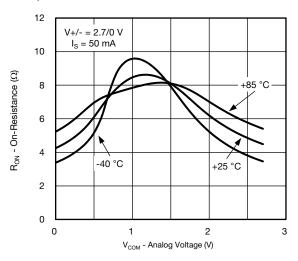
R_{ON} vs. V_{COM} and Supply Voltage



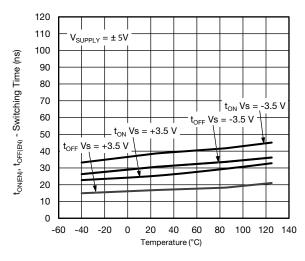
R_{ON} vs. Analog Voltage and Temperature



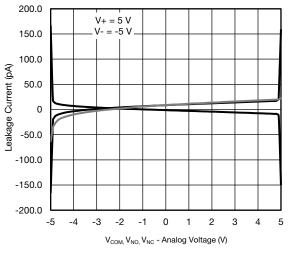
Switching Time vs. Temperature and Single Supply Voltage



R_{ON} vs. Analog Voltage and Temperature



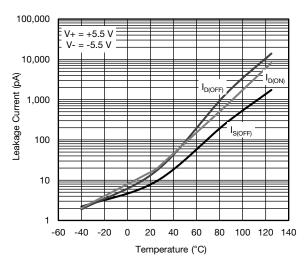
Switching Time vs. Temperature and Dual Supply Voltage



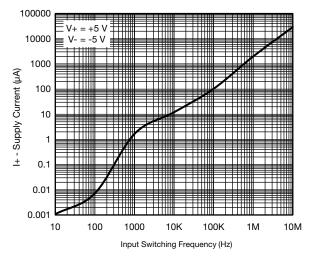
Leakage Current vs. Analog Voltage

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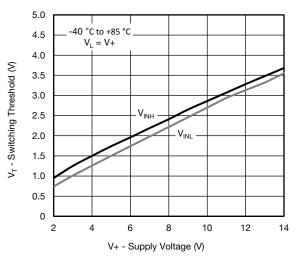
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



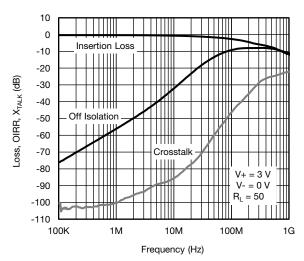
Leakage Current vs. Temperature



Switching Current vs. Input Switching Frequency

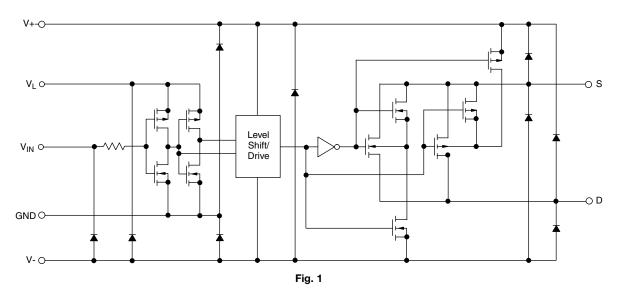


Switching Threshold vs. Supply Voltage



Insertion Loss, Off Isolation and Crosstalk vs. Frequency

SCHEMATIC DIAGRAM (typical channel)



TEST CIRCUITS

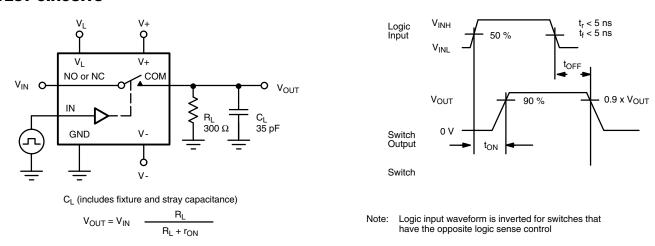


Fig. 2 - Switching Time

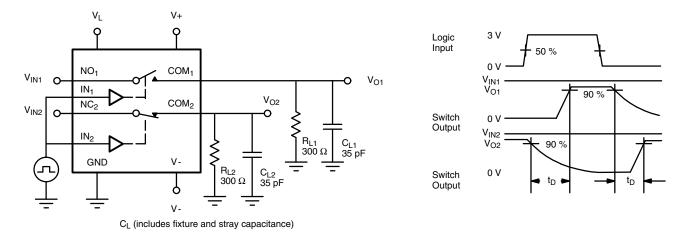
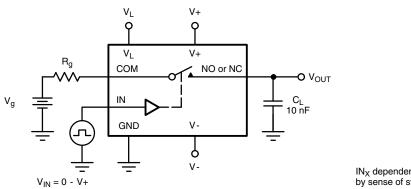
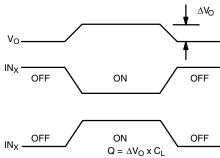


Fig. 3 - Break-Before-Make (DG9426E)

TEST CIRCUITS





 $\ensuremath{\mathsf{IN}}_X$ dependent on switch configuration Input polarity determined by sense of switch.

Fig. 4 - Charge Injection

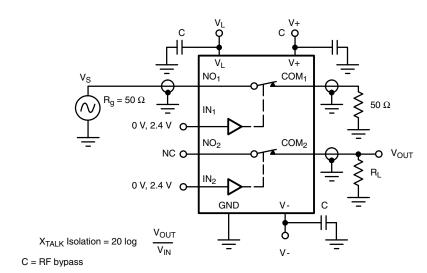


Fig. 5 - Crosstalk

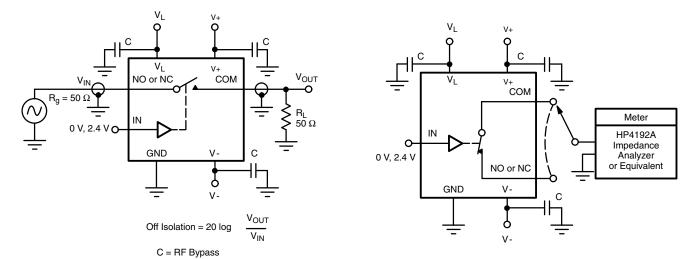


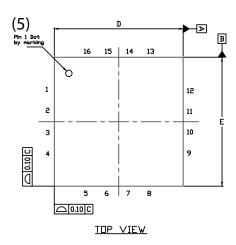
Fig. 6 - Off-Isolation

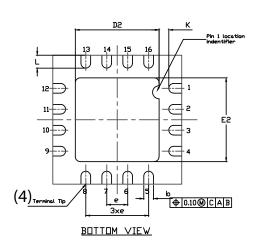
Fig. 7 - Source/Drain Capacitances

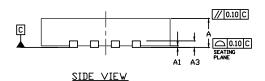
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QFN 4x4-16L Case Outline







	VARIATION 1					VARIATION 2							
DIM	МІ	MILLIMETERS(1)		INCHES		INCHES MILLIMETERS ⁽¹⁾ IN		INCHES MILLIMETERS ⁽¹⁾		MILLIMETERS ⁽¹⁾		INCHES	
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	0.75	0.85	0.95	0.029	0.033	0.037	0.75	0.85	0.95	0.029	0.033	0.037	
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002	
A3		0.20 ref.			0.008 ref.			0.20 ref.			0.008 ref.		
b	0.25	0.30	0.35	0.010	0.012	0.014	0.25	0.30	0.35	0.010	0.012	0.014	
D		4.00 BS0)		0.157 BSC 4.00 BSC 0.		0.157 BSC						
D2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106	
е		0.65 BS0			0.026 BSC			0.65 BSC		0.026 BSC			
Е		4.00 BS0			0.157 BSC			4.00 BSC 0.157 BSC					
E2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106	
K		0.20 min			0.008 min. 0.20 min. 0.00		0.20 min.		0.008 min.				
L	0.5	0.6	0.7	0.020	0.024	0.028	0.3	0.4	0.5	0.012	0.016	0.020	
N ⁽³⁾		16			16		16		16				
Nd ⁽³⁾		4			4 4 4		4		4				
Ne ⁽³⁾		4		4 4 4			4						

Notes

- (1) Use millimeters as the primary measurement.
- (2) Dimensioning and tolerances conform to ASME Y14.5M. 1994.
- (3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
- (4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
- (5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
- (6) Package warpage max. 0.05 mm.

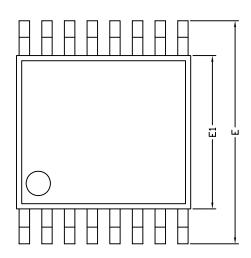
ECN: S13-0893-Rev. B, 22-Apr-13

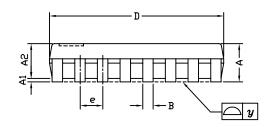
DWG: 5890

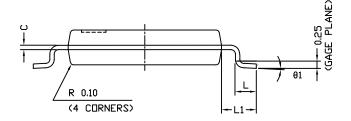
Revision: 22-Apr-13



TSSOP: 16-LEAD







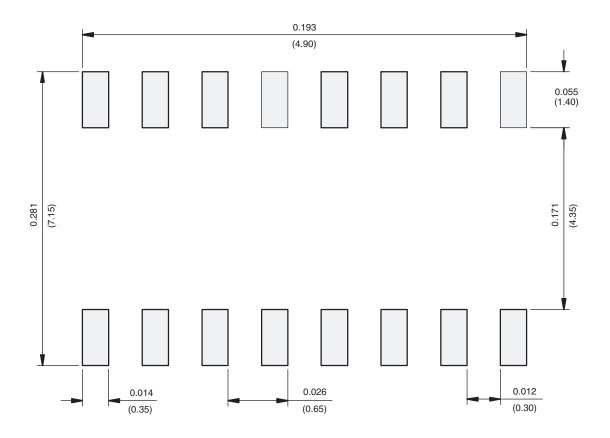
	DIMENSIONS IN MILLIMETERS								
Symbols	Min	Nom	Max						
А	=	1.10	1.20						
A1	0.05	0.10	0.15						
A2	=	1.00	1.05						
В	0.22	0.28	0.38						
С	=	0.127	-						
D	4.90	5.00	5.10						
E	6.10	6.40	6.70						
E1	4.30	4.40	4.50						
е	-	0.65	-						
L	0.50	0.60	0.70						
L1	0.90	1.00	1.10						
у	=	-	0.10						
θ1	0°	3°	6°						
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RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads Dimensions in inches (mm)



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